Rev. B, February 2000



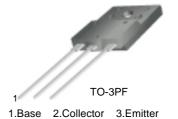
### KSC5803

# High Voltage Color Display Horizontal Deflection Output (No Damper Diode)

High Breakdown Voltage: BV<sub>CBO</sub>=1500V
High Speed Switching: t<sub>F</sub>=0.1µs (Typ.)

• Wide S.O.A

• For C-Monitor(85KHz)



### **NPN Triple Diffused Planar Silicon Transistor**

### Absolute Maximum Ratings $T_C=25$ °C unless otherwise noted

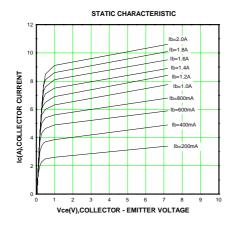
Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage	1500	V
V <sub>CEO</sub>	Collector-Emitter Voltage	800	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current (DC)	12	Α
I <sub>CP</sub>	Collector Current (Pulse)	24	Α
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	70	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

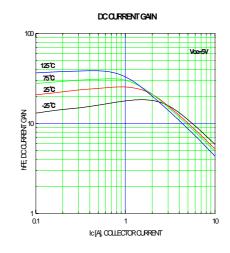
### Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

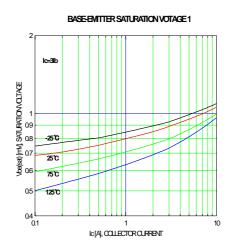
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CES</sub>	Collector Cut-off Current	V <sub>CE</sub> = 1400V, V <sub>BE</sub> =0			1	mA
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CE} = 800V, I_{E} = 0$			10	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 4V, I_{C} = 0$			1	mA
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 1A$	15		40	
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 8A$	5.5		8.5	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 8A, I_B = 2A$			3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	$I_C = 8A, I_B = 2A$			1.5	V
t <sub>STG</sub>	Storage Time	$V_{CC} = 200V, I_{C} = 7A$			4	μs
t <sub>F</sub>	Fall Time	$I_{B1} = 1.4A, I_{B2} = -2.8A$ $R_L = 28.6\Omega$			0.3	μs

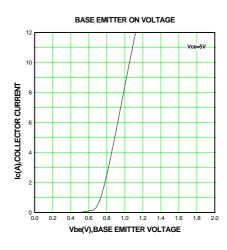
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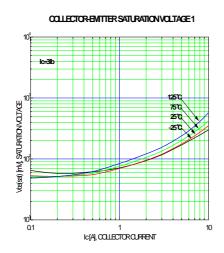
# **Typical Characteristics**







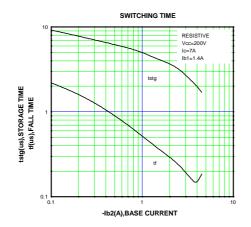


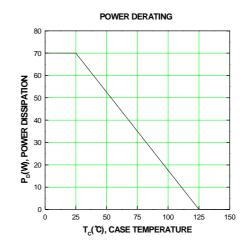




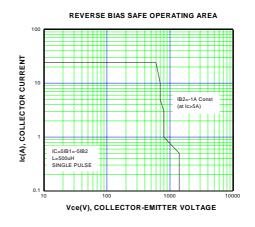
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# **Typical Characteristics** (continued)



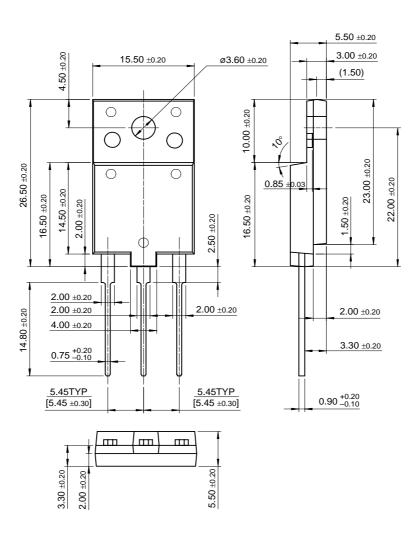


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# **Package Dimenisons**

# TO-3PF



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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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